# **TRIACS**

Glass-passivated 4 Ampere triacs intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance with very low thermal resistances. These triacs feature a high surge current capability and a range of gate current sensitivities between 5 and 50 mA. Typical applications include AC power control circuits such as motor, industrial lighting, industrial and domestic heating control and static switching systems.

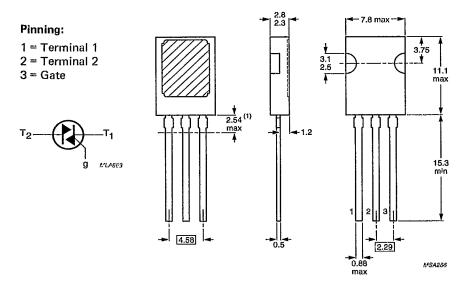
## **QUICK REFERENCE DATA**

		BT134	I—500   600		700	800		
Repetitive peak off-state voltage	$v_{DRM}$	max.	500	600	700	800	٧	
RMS on-state current	IT(RMS)	max.				Α		
Non-repetitive peak on-state current at 50 Hz at 60 Hz	ITSM ITSM	max. max.					A A	

## **MECHANICAL DATA**

Fig.1 SOT-82.

Dimensions in mm



(1) Within this region the cross-section of leads is uncontrolled.

Net mass: 0.8 g.

Note: The exposed metal mounting base is directly connected to terminal T2.

Supplied on request: accessories (see data sheets Mounting instructions and accessories for SOT-82

envelopes).

### **RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134),

Voltages (in either direction)	BT134-500		600	700	800		
Non-repetitive peak off-state voltage (t ≤ 10 ms)†	V <sub>DSM</sub>	max.	500*	600*	700*	800	V
Repetitive peak off-state voltage $(\delta \le 0.01)$ †	$v_{DRM}$	max.	500	600	700	800	V
Crest working off-state voltage	$v_{DWM}$	max.	400	400	400	400	٧
Currents (in either direction)							
RMS on-state current (conduction angle 360°) up to T <sub>mb</sub> = 102 °C	<sup>I</sup> T(RMS)	max.	4				Α
Average on-state current for half-cycle operation (averaged over any 20 ms period) up to $T_{mb} = 92$ °C	<sup>I</sup> T(AV)	max.		2	.5		A
Repetitive peak on-state current	ITRM	max.	25				Α
Non-repetitive peak on-state current; $T_j = 120$ °C prior to surge; full sinewave t = 20 ms	1704	max.		-	25		Α
t = 16.7 ms	ITSM ITSM	max.			.0 80		Ä
$l^2t$ for fusing (t = 10 ms)	l <sup>2</sup> t	max.		4			A²s
Rate of rise of on-state current after triggering with $I_G = 200$ mA to $I_T = 6$ A; $dI_G/dt = 0.2$ A/ $\mu$ s	dl <sub>T</sub> /dt	max.		1	0		A/μs
Gate to terminal 1							
Power dissipation  Average power dissipation							
(averaged over any 20 ms period)	P <sub>G</sub> (AV)	max.		0	.5		W
Peak power dissipation	PGM	max.			W		
Temperatures							
Storage temperature	T <sub>stg</sub>	40 to +125				oC	
Operating junction temperature full-cycle operation half-cycle operation	T <sub>j</sub> Tj	max. max.		12 11	-		oC oC

<sup>†</sup>For BT134-500D/600D use  $R_{(G-T_1)} = 1 \text{ k}\Omega$ .

<sup>\*</sup>Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch into the on-state. The rate of rise of on-state current should not exceed 3 A/ $\mu$ s.

THERMAL RESISTANCE					
From junction to mounting base					
full-cycle operation	R <sub>th j-mb</sub>	=	3.0	K/W	
half-cycle operation	R <sub>th j-mb</sub>	=	3.7	K/W	
Transient thermal impedance; t = 1 ms	Z <sub>th j-mb</sub>	=	0.6	K/W	
Influence of mounting method					
1. Heatsink mounted with clip (see mounting instructions)					
Thermal resistance from mounting base to heatsink					
a. with heatsink compound	R <sub>th mb-h</sub>	=	0.3	K/W	
b. with heatsink compound and 0.06 mm maximum mica					

# 2. Free-air operation

insulator (56354)

c. without heatsink compound

The quoted value of  $R_{th\ j-a}$  should be used only when no leads of other dissipating components run to the same tie-point.

Thermal resistance from junction to ambient in free air: mounted on a printed-circuit board at any lead length

 $R_{th j-a} = 100 \text{ K/W}$ 

Rth mb-h

Rth mb-h

1.4

1.4

K/W

K/W

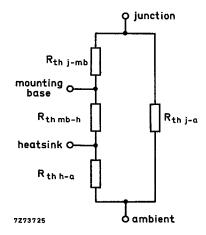


Fig.2 Components of thermal resistance.

## **CHARACTERISTICS**

Polarities, positive or negative, are identified with respect to T<sub>1</sub>.

Voltages	and	curren	ts (	in	either	direction	۱

Voitages and carreits (in eliner direction)								
On-state voltage (measured under pulse conditions to prevent excessive $I_T = 5 \text{ A}$ ; $T_j = 25  ^{\text{O}}\text{C}$				sive dissip VT	ation)	<	1.70	V
Rate of rise of off-state voltage that will not trigger any device; T <sub>j</sub> = 120 °C; gate open circuit BT134 series GBT134 series GBT134 series FBT134 series EBT134 series EBT134 series EBT134 series EBT134—500D/600D			dVD dVD dVD	/dt /dt /dt	< < < typ.		V/μs V/μs V/μs V/μs V/μs	
Rate of change of commutating voltage the trigger any device when —dI <sub>com</sub> /dt = 1 IT(RMS) = 4 A; T <sub>mb</sub> = 85 °C; gate ope BT134 series GBT134 series F	.8 A/ms;	_	'DWMm:	dV <sub>cc</sub>	<sub>om</sub> /dt <sub>om</sub> /dt <sub>om</sub> /dt	typ.	10	V/μs V/μs V/μs
Off-state current VD = VDWMmax; Tj = 120 °C Gate voltage that will trigger all devices				I <sub>D</sub> V <sub>GT</sub>		< >	0.5 1.5	mĄ. V
Gate voltage that will not trigger any device $V_D = V_{DWMmax}$ ; $T_j = 120$ °C; $T_2$ and G positive or negative	ce			$v_{\sf GD}$		<	250	mV
Gate current that will trigger all devices (I	GT); G to	Т1						
Holding current (I <sub>H</sub> ) T <sub>2</sub> +			T <sub>2</sub> +	T <sub>2</sub> -	-	T <sub>2</sub> -		
Latching current (I <sub>L</sub> ); $V_D = 12 \text{ V}$ ; $T_j = 25 ^{\circ}\text{C}$ G+			G+	G—	G-		G+	
BT134 series	IGT IH IL	> < <	35 15 20	35 15 30	35 15 20		70 15 30	mA mA mA
BT134 series G	IGT IH IL	> < <	50 30 30	50 30 45	50 30 30		100 30 45	mA mA mA
BT134 series F	IGT IH IL	> < <	25 15 20	25 15 30	25 15 20		70 15 30	mA mA mA
BT134 series E	IGT IH IL	> < <	10 15 15	10 15 20	10 15 15		25 15 20	mA mA mA
BT134-500D/600D	IGT IH IL	> < <	5 10 10	5 10 15	5 10 10		10 10 15	mA mA mA

 $<sup>{}^*\</sup>mathsf{R}_{\left(\mathsf{G-T}_1\right)}=1\,\mathsf{k}\Omega.$ 

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MOUNTING INSTRUCTIONS

- The device may be soldered directly into the circuit. The maximum permissible soldering temperature is 275 °C. Heat must not be applied for more than 5 seconds. Soldered joints must be at least 4.7 mm from the body of the device.
- 2. The leads must not be bent less than 2.4 mm from the body of the device and should be supported during bending. The leads can be bent, twisted or straightened by 90° maximum. The minimum bending radius is 1 mm.
- Any heatsink used must have a flatness in the mounting area of 0.02 mm maximum per 10 mm. Mounting holes must be deburred.
- For spring-clip mounting a metallic-oxide loaded heatsink compound must be used to ensure good thermal contact between the mounting-base and heatsink. Ordinary silicone grease is not recommended.
- 5. Body mounting of the device into a hybrid circuit is possible either by soldering or by adhesive. For soldering either a copper-plate or anodized aluminium-plate with a copper layer are recommended. The device can be adhesively mounted to a ceramic substrate.
- 6. Any solder or adhesive layer used for body mounting must be as thin as possible with all air voids eliminated. This prevents excessive heat rise within the device,

#### **OPERATING NOTES**

Dissipation and heatsink considerations:

a. The method of using Fig.3 is as follows: Starting with the required current on the I<sub>T(AV)</sub> or I<sub>T(RMS)</sub> axis, trace upwards to meet the appropriate form factor or conduction angle curve. Trace horizontally and upwards from the appropriate value on the T<sub>amb</sub> scale. The intersection determines the R<sub>th mb-a</sub>. The heatsink thermal resistance value (R<sub>th h-a</sub>) can now be calculated from:

Rth h-a = Rth mb-a - Rth mb-h.

b. Any measurement of heatsink temperature should be made immediately adjacent to the device.

# **BT134 SERIES**



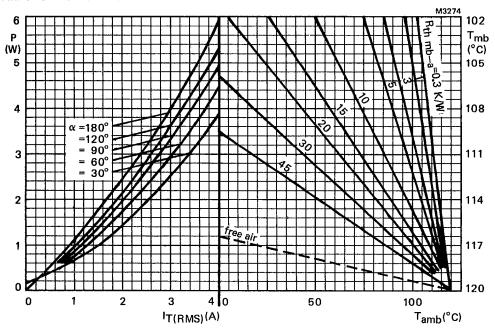


Fig.3 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.

$$\alpha_1$$
  $\alpha_2$   $\alpha_1 = \alpha_2$ : conduction angle per half cycle

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### OVERLOAD OPERATION

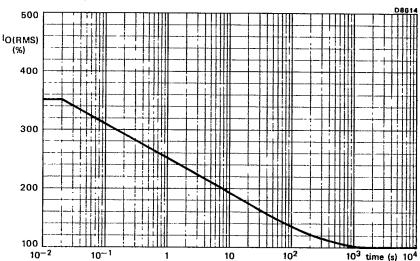


Fig.4 Maximum permissible duration of steady overload (provided that T<sub>mb</sub> does not exceed 120 °C during and after overload) expressed as a percentage of the steady state r.m.s. rated current. For high r.m.s. overload currents precautions should be taken so that the temperature of the terminals does not exceed 125 °C. During these overload conditions the triac may lose control. Therefore the overload should be terminated by a separate protection device.

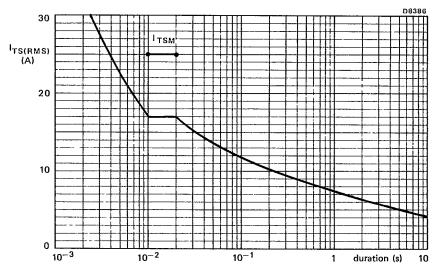
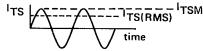


Fig.5 Maximum permissible non-repetitive r.m.s. on-state current based on sinusoidal currents (f = 50 Hz);  $T_j = 120$  °C prior to surge. The triac may temporarily lose control following the surge.



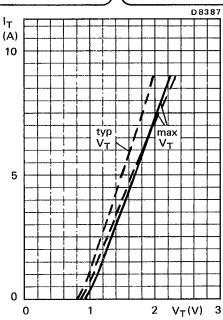


Fig.6 On state voltage drop.

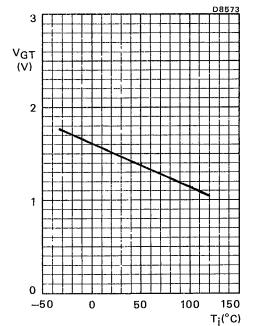
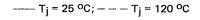


Fig. 7 Minimum gate voltage that will trigger all devices; all conditions.



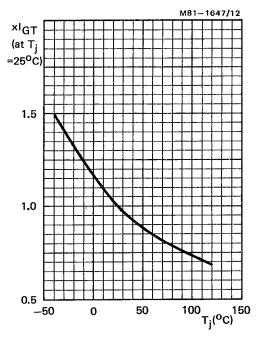


Fig.8 Normalised gate current that will trigger all devices; all conditions.

**Triacs** 

**BT134 SERIES** 

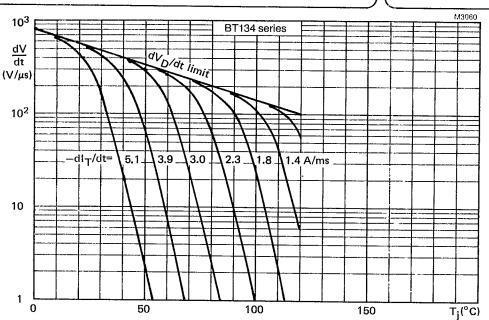


Fig.9 Typical commutation dV/dt for BT134 series versus  $T_{j}$ . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation dl<sub>T</sub>/dt.

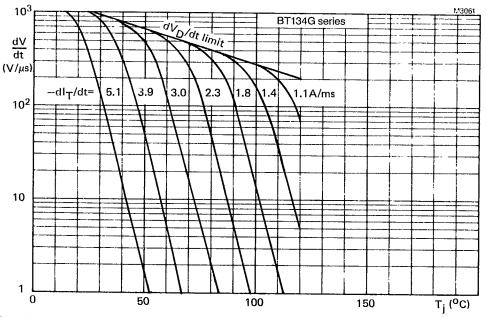


Fig.10 Limit commutation dV/dt for BT134G series versus  $T_j$ . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation dl<sub>T</sub>/dt.

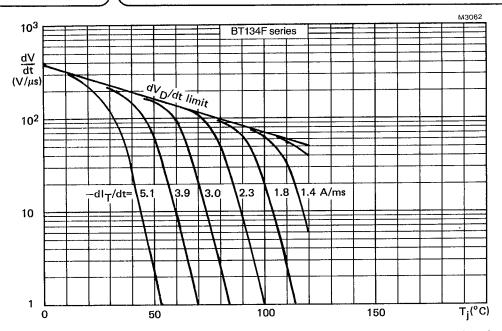


Fig.11 Typical commutation dV/dt for BT134F series versus  $T_j$ . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation  $dl_T/dt$ .

